TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

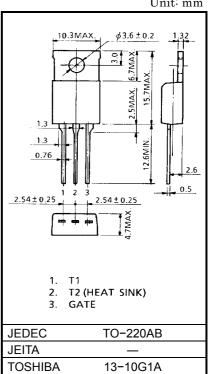
SM6G45, SM6J45, SM6G45A, SM6J45A

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V_{DRM} = 400, 600V
- **R.M.S ON-State Current** .
- : IT (RMS) = 6A
- High Commutating (dv / dt)

MAXIMUM RATINGS

CHARACTERI	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off− State Voltage	SM6G45 SM6G45A	V _{DRM}	400	V	
	SM6J45 SM6J45A	VDRM	600		
R.M.S On-State Curren (Full Sine Waveform Tc	•	I _{T (RMS)}	6	А	
Peak One Cycle Surge On-State		l	60 (50Hz)	А	
Current (Non-Repetitive	2)	ITSM	66 (60Hz)	~	
I ² t Limit Value		l ² t	18	A ² s	
Critical Rate of Rise of C Current	0n−State	di / dt	50	Α/μs	
Peak Gate Power Dissip	ation	P _{GM}	5	W	
Average Gate Power Dis	ssipation	P _{G (AV)}	0.5	W	
Peak Gate Voltage		V _{GM}	10	V	
Peak Gate Current		I _{GM}	2	А	
Junction Temperature		Тј	-40~125	°C	
Storage Temperature Ra	ange	T _{stg}	-40~125	°C	



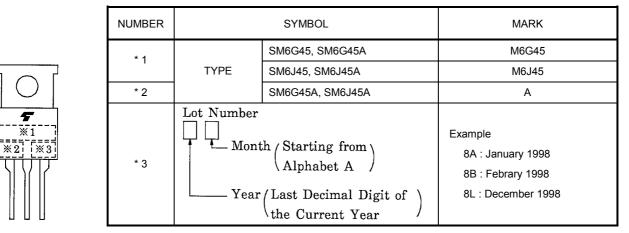
Weight: 2.0g

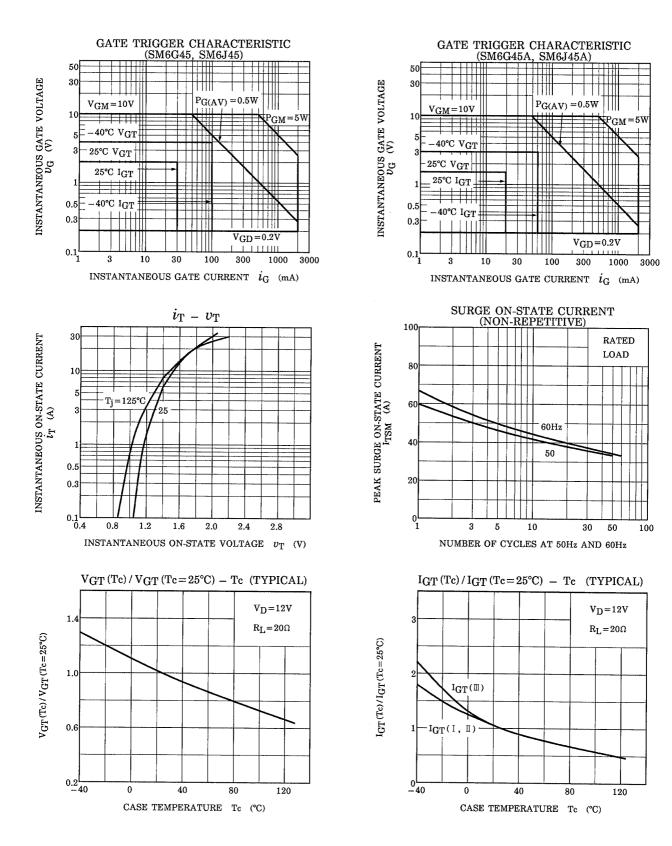
Unit: mm

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

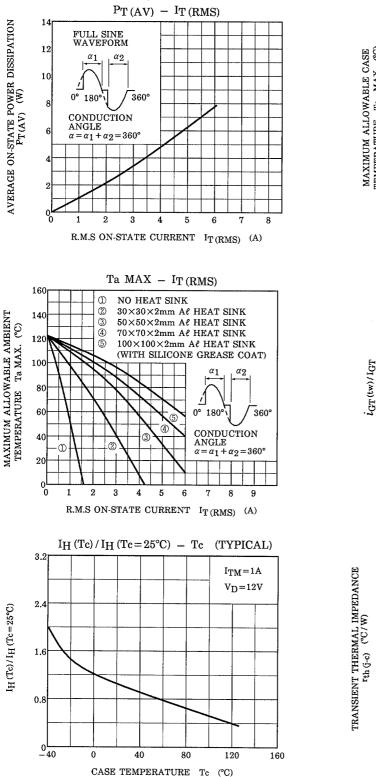
CHARACTERISTIC			SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated, T _j = 125°C		_	_	2	mA		
Gate Trigger Voltage			I	V _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)		_	2	- V
	SM6G45 SM6J45	5	Ш			T2 (+), Gate (−)	_	_	2	
		5	Ш			T2 (-), Gate (-)	_	_	2	
			IV			T2 (-), Gate (+)	_	_	_	
			I			T2 (+), Gate (+)		_	1.5	
	SM6G45/ SM6J45A	5A	Ш			T2 (+), Gate (-)		_	1.5	
		δA	III			T2 (-), Gate (-)		_	1.5	
			IV			T2 (-), Gate (+)		_	—	
Gate Trigger Current	SM6G45 SM6J45		I	I _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)		_	30	- mA
		5	Ш			T2 (+), Gate (-)		_	30	
		5	III			T2 (-), Gate (-)		_	30	
			IV			T2 (-), Gate (+)		_	_	
	SM6G45		I			T2 (+), Gate (+)		_	20	
		5A	Ш			T2 (+), Gate (-)		_	20	
	SM6J45	δA	III			T2 (-), Gate (-)		_	20	
			IV	1		T2 (-), Gate (+)		_	_	
Peak On-State Voltage			V _{TM}	I _{TM} = 9A		-	_	1.5	V	
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V		
Holding Current			Ι _Η	V _D = 12V, I _{TM} = 1A		_	_	50	mA	
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC		_	_	2.5	°C/W		
Critical Rate of SM6G Rise of Off-SM6J			(a), (a)) -	V _{DRM} = 400V, (di / dt) c = -3.3A / ms		10	_	_	V / µs	
State Voltage at Commutation		SM6G45A SM6J45A		(dv / dt) c	(a1 / a1) c = -3.3A / ms T _j = 125°C		4	—	_	v / µs

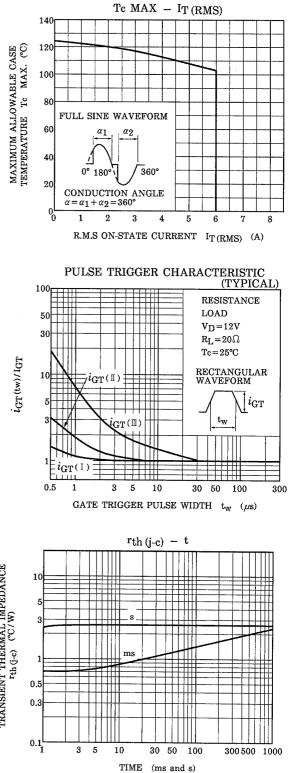
MARKING





TOSHIBA





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